

L Number	Hits	Search Text	DB	Time stamp
1	433	gan adj substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 08:58
2	157	((gan adj substrate) and mocvd	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:09
3	39	((gan adj substrate) and mocvd) and oxygen	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:04
4	35	((gan adj substrate) and mocvd) and (silane teos)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:09
5	11	((gan adj substrate) and mocvd) and (silane teos)) and oxygen	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:10
6	2	((gan adj substrate) and mocvd) and 'transport gas'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:09
7	90	(gan adj substrate) and hvpe	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:09
8	29	((gan adj substrate) and hvpe) and (silane teos)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:09
9	10	((gan adj substrate) and hvpe) and (silane teos)) and oxygen	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/23 09:10